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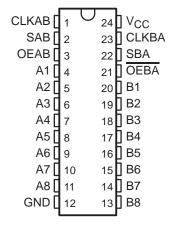
- Bus Transceivers/Registers
- Independent Registers and Enables for A and B Buses
- Multiplexed Real-Time and Stored Data
- Choice of True or Inverting Data Paths
- Choice of 3-State or Open-Collector Outputs to A Bus
- Package Options Include Plastic Small-Outline (DW) Packages, Ceramic Chip Carriers (FK), and Standard Plastic (NT) and Ceramic (JT) 300-mil DIPs

DEVICE	A OUTPUT	B OUTPUT	LOGIC	
SN74ALS651A, 'AS651	3 State	3 State	Inverting	
SN54ALS652, SN74ALS652A, 'AS652	3 State	3 State	True	
'ALS653	Open Collector	3 State	Inverting	
SN74ALS654	Open Collector	3 State	True	

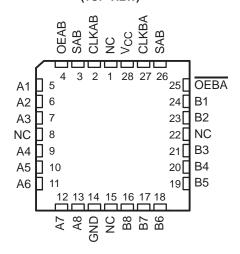
description

These devices consist of bus-transceiver circuits, D-type flip-flops, and control circuitry arranged for multiplexed transmission of data directly from the data bus or from the internal storage registers. Output-enable (OEAB and OEBA) inputs are provided to control the transceiver functions. Select-control (SAB and SBA) inputs are provided to select real-time or stored data transfer. The circuitry used for select control eliminates the typical decoding glitch that occurs in a multiplexer during the transition between stored and real-time data. A low input level selects real-time data, and a high input level selects stored data. Figure 1

SN54ALS', SN54AS' . . . JT PACKAGE SN74ALS', SN74AS' . . . DW OR NT PACKAGE (TOP VIEW)



SN54ALS', SN54AS' . . . FK PACKAGE (TOP VIEW)



NC - No internal connection

illustrates the four fundamental bus-management functions that can be performed with the octal bus transceivers and registers.

Data on the A or B data bus, or both, can be stored in the internal D-type flip-flops by low-to-high transitions at the appropriate clock (CLKAB or CLKBA) terminals, regardless of the select- or output-control terminals. When SAB and SBA are in the real-time transfer mode, it is possible to store data without using the internal D-type flip-flops by simultaneously enabling OEAB and OEBA. In this configuration, each output reinforces its input. When all other data sources to the two sets of bus lines are at high impedance, each set of bus lines remains at its last state.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



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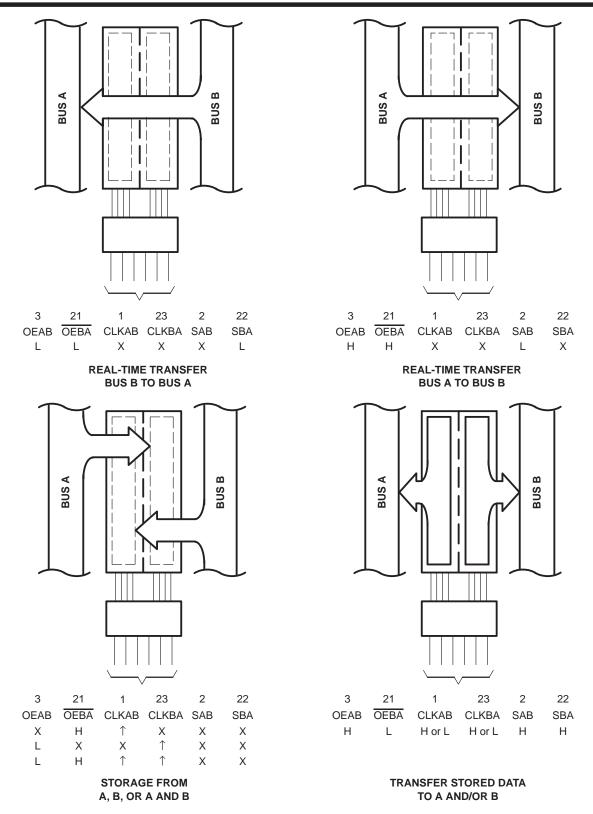
description (continued)

The -1 versions of the SN74ALS651A and SN74ALS652A are identical to the standard versions except that the recommended maximum I_{OL} for the -1 versions is increased to 48 mA. There are no -1 versions of the SN54ALS652, SN54ALS653, SN74ALS653, and SN74ALS654.

The SN54ALS' and SN54AS' families are characterized for operation over the full military temperature range of –55°C to 125°C. The SN74ALS' and SN74AS' families are characterized for operation from 0°C to 70°C.



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Pin numbers are for the DW, JT, and NT packages.

Figure 1. Bus-Management Functions



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FUNCTION TABLES

SN54ALS653, SN54AS651, SN74ALS651A, SN74ALS653, SN74AS651

		INPU ⁻	гѕ			DATA	4 1/0†	OPERATION OR FUNCTION
OEAB	OEBA	CLKAB	CLKBA	SAB	SBA	A1-A8	B1-B8	OPERATION OR FONCTION
L	Н	H or L	H or L	Х	Х	Input	Input	Isolation
L	Н	\uparrow	\uparrow	X	Х	Input	Input	Store A and B data
Х	Н	1	H or L	Х	Х	Input	Unspecified [‡]	Store A, hold B
Н	Н	1	\uparrow	X [‡]	X	Input	Output	Store A in both registers
L	Х	H or L	1	Х	Х	Unspecified [‡]	Input	Hold A, store B
L	L	\uparrow	\uparrow	X	X‡	Output	Input	Store B in both registers
L	L	Х	Х	Х	L	Output	Input	Real-time B data to A bus
L	L	Χ	H or L	X	Н	Output	Input	Stored B data to A bus
Н	Н	Х	Х	L	Х	Input	Output	Real-time A data to B bus
Н	Н	H or L	Χ	Н	Х	Input	Output	Stored A data to B bus
Н	L	H or L	H or L	Н	Н	Output	Output	Stored A data to B bus and stored B data to A bus

[†] The data output functions may be enabled or disabled by a variety of level combinations at OEAB or OEBA. Data input functions are always enabled; i.e., data at the bus terminals is stored on every low-to-high transition on the clock inputs.

Select control = H; clocks must be staggered to load both registers.

SN54ALS652, SN54AS652, SN74ALS652A, SN74ALS654, SN74AS652

		INPU ⁻	гѕ			DATA	\ I/O†	OPERATION OR FUNCTION
OEAB	OEBA	CLKAB	CLKBA	SAB	SBA	A1-A8	B1-B8	OPERATION OR FUNCTION
L	Н	H or L	H or L	Х	Х	Input	Input	Isolation
L	Н	↑	1	Χ	X	Input	Input	Store A and B data
Х	Н	↑	H or L	Х	Х	Input	Unspecified [‡]	Store A, hold B
Н	Н	\uparrow	\uparrow	X [‡]	X	Input	Output	Store A in both registers
L	Х	H or L	1	Х	Х	Unspecified [‡]	Input	Hold A, store B
L	L	\uparrow	\uparrow	X	X‡	Output	Input	Store B in both registers
L	L	Х	Х	Х	L	Output	Input	Real-time B data to A bus
L	L	Χ	H or L	X	Н	Output	Input	Stored B data to A bus
Н	Н	Χ	Χ	L	Х	Input	Output	Real-time A data to B bus
Н	Н	H or L	Χ	Н	X	Input	Output	Stored A data to B bus
Н	L	H or L	H or L	Н	Н	Output	Output	Stored A data to B bus and stored B data to A bus

[†] The data output functions may be enabled or disabled by a variety of level combinations at OEAB or OEBA. Data input functions are always enabled; i.e., data at the bus terminals is stored on every low-to-high transition on the clock inputs.

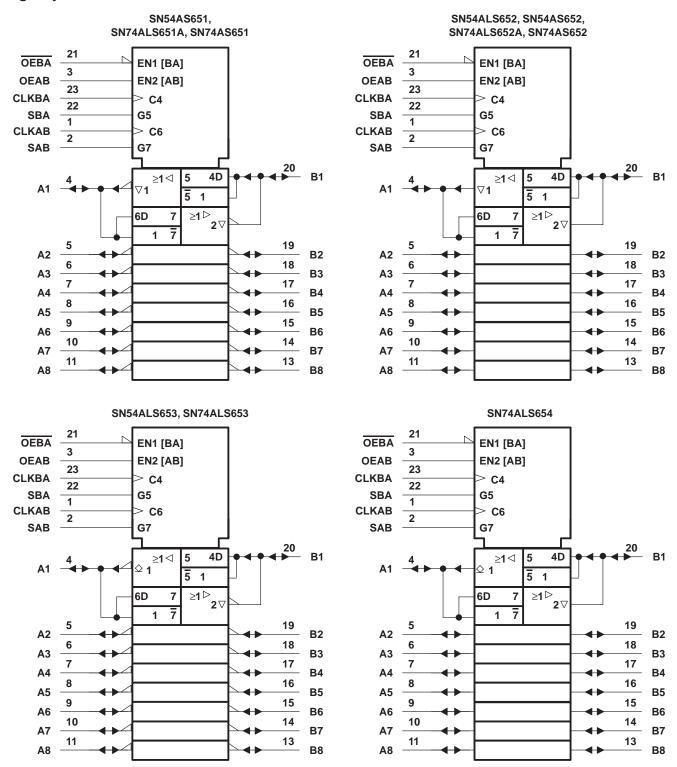
Select control = H; clocks must be staggered to load both registers.



[‡] Select control = L; clocks can occur simultaneously.

[‡] Select control = L; clocks can occur simultaneously.

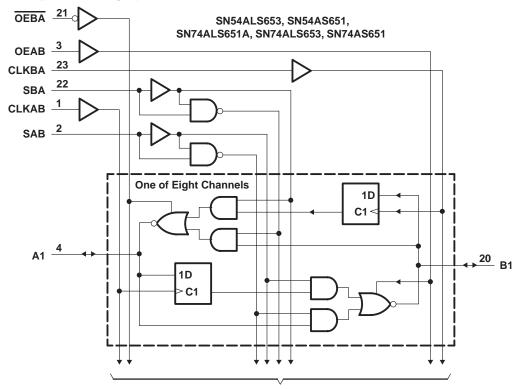
logic symbols†



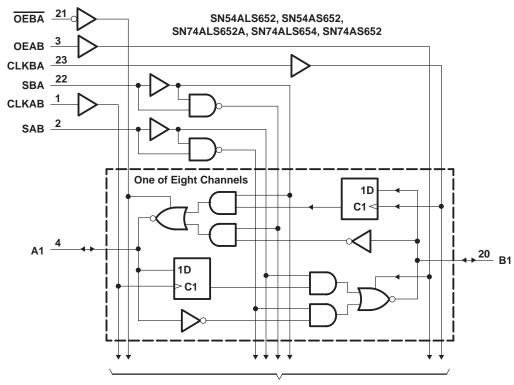
[†]These symbols are in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12. Pin numbers shown are for the DW, JT, and NT packages.



logic diagrams (positive logic)



To Seven Other Channels



To Seven Other Channels

Pin numbers shown are for the DW, JT, and NT packages.



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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage, V _{CC}	
Input voltage, V _I : Control inputs	7 V
I/O ports	5.5 V
Operating free-air temperature range, T _A : SN54ALS652	. −55°C to 125°C
SN74ALS651A, SN74ALS652A	0°C to 70°C
Storage temperature range, T _{stg}	-65°C to 150°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

recommended operating conditions

			SN7	'4ALS65	1A	UNIT
			MIN	NOM	MAX	UNIT
Vcc	Supply voltage				5.5	V
V _{IH}	High-level input voltage		2			V
V_{IL}	Low-level input voltage				0.8	V
ІОН	High-level output current				-15	mA
	I _{OL} Low-level output current				24	
IOL					48‡	mA
fclock	Clock frequency		0		40	MHz
	Pulse duration	CLKBA or CLKAB high	12.5			
t _W	Pulse duration	CLKBA or CLKAB low	12.5			ns
t _{su}	Setup time before CLKAB↑ or CLKBA↑	A or B	10			ns
th	Hold time after CLKAB↑ or CLKBA↑	A or B	0			ns
TA	Operating free-air temperature		0		70	°C

[‡] Applies only to the SN74ALS651A-1 and only if V_{CC} is maintained between 4.75 V and 5.25 V

recommended operating conditions

			SN	54ALS6	52	SN74ALS652A			UNIT	
			MIN	NOM	MAX	MIN	NOM	MAX	UNII	
Vсс	Supply voltage		4.5	5	5.5	4.5	5	5.5	V	
VIH	High-level input voltage		2			2			V	
VIL	Low-level input voltage				0.7			0.8	V	
loн	High-level output current				-12			-15	mA	
					12			24	1	
lOL	Low-level output current							48‡	mA	
fclock	Clock frequency		0		35	0		40	MHz	
	Pulse duration	CLKBA or CLKAB high	14.5	•		12.5				
t _W	Pulse duration	CLKBA or CLKAB low	14.5	•		12.5			ns	
t _{su}	Setup time before CLKAB↑ or CLKBA↑	A or B	15			10			ns	
t _h	Hold time after CLKAB↑ or CLKBA↑	A or B	5			0			ns	
T _A	Operating free-air temperature	-	-55		125	0		70	°C	

[‡] Applies only to the SN74ALS652A-1 and only if V_{CC} is maintained between 4.75 V and 5.25 V



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electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

	DADAMETED	TF07.00	TEST CONDITIONS			SN74ALS651A			
	PARAMETER	TEST CO	NUTTIONS	MIN	TYP [†]	MAX	UNIT		
VIK		V _{CC} = 4.5 V,	I _I = -18 mA			-1.2	V		
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V},$	$I_{OH} = -0.4 \text{ mA}$	V _{CC} -2					
Vон		V _{CC} = 4.5 V	$I_{OH} = -3 \text{ mA}$	2.4	3.2		V		
		VCC = 4.5 V	$I_{OH} = -15 \text{ mA}$	2					
		V _{CC} = 4.5 V	I _{OL} = 12 mA		0.25	0.4			
VOL		VCC = 4.5 V	I _{OL} = 24 mA		0.35 0.5		V		
		$V_{CC} = 4.75 V,$	I _{OL} = 48 mA (-1 versions)		0.35	0.5			
1.	Control inputs	V _{CC} = 5.5 V,	$V_I = 7 V$			0.1	mA		
11	A or B ports	V _{CC} = 5.5 V,	V _I = 5.5 V			0.1	IIIA		
	Control inputs	V 55V	V _I = 2.7 V			20	^		
ΊΗ	A or B ports [‡]	$V_{CC} = 5.5 \text{ V},$				20	μΑ		
	Control inputs	V 55V	V 0.4V			-0.2	^		
IIL.	A or B ports‡	$V_{CC} = 5.5 \text{ V},$	V _I = 0.4 V			-0.2	-0.2 mA		
IO§		V _{CC} = 5.5 V,	V _O = 2.25 V	-30		-112	mA		
			Outputs high		42	68			
ICC		V _{CC} = 5.5 V	Outputs low	52		82	mA		
			Outputs disabled		52	82			

 $[\]dagger$ All typical values are at $V_{CC} = 5 \text{ V}$, $T_A = 25^{\circ}\text{C}$.

[‡] For I/O ports, the parameters I_{IH} and I_{IL} include the off-state output current.

[§] The output conditions have been chosen to produce a current that closely approximates one-half of the true short-circuit output current, IOS.

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electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

	DAMETED	TEST CONDITIONS		SN	54ALS6	52	SN7	4ALS65	2A	LINUT	
PF	RAMETER	1531	CONDITIONS	MIN	TYP†	MAX	MIN	TYP [†]	MAX	UNIT	
٧IK		V _{CC} = 4.5 V,	$I_{I} = -18 \text{ mA}$			-1.2			-1.2	V	
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V},$	$I_{OH} = -0.4 \text{ mA}$	V _{CC} -2			V _{CC} -2				
\/a			$I_{OH} = -3 \text{ mA}$	2.4	3.2		2.4	3.2		V	
∨он		V _{CC} = 4.5 V	I _{OH} = -12 mA	2						V	
			I _{OH} = -15 mA				2				
		V _{CC} = 4.5 V	I _{OL} = 12 mA		0.25	0.4		0.25	0.4		
VOL		VCC = 4.5 V	I _{OL} = 24 mA					0.35	0.5	V	
		$V_{CC} = 4.75 \text{ V},$	I _{OL} = 48 mA (-1 versions)					0.35	0.5		
1.	Control inputs	V _{CC} = 5.5 V,	V _I = 7 V			0.1			0.1	mA	
11	A or B ports	$V_{CC} = 5.5 V,$	V _I = 5.5 V			0.1			0.1	IIIA	
	Control inputs	V 55V	V: 07V			20			20	^	
ΊΗ	A or B ports‡	V _{CC} = 5.5 V,	V _I = 2.7 V		20				μΑ		
	Control inputs	V 55V	V 04V			-0.2			-0.2	4	
¹ L	A or B ports‡	V _{CC} = 5.5 V,	V _I = 0.4 V			-0.2			-0.2	mA	
IO§	-	V _{CC} = 5.5 V,	V _O = 2.25 V	-20		-112	-30		-112	mA	
			Outputs high		47	76		47	76		
ICC		V _{CC} = 5.5 V	Outputs low		55	88		55	88	mA	
			Outputs disabled		55	88		55	88		

[†] All typical values are at $V_{CC} = 5 \text{ V}$, $T_A = 25^{\circ}\text{C}$.

[‡] For I/O ports, the parameters I_{IH} and I_{IL} include the off-state output current.

[§] The output conditions have been chosen to produce a current that closely approximates one-half of the true short-circuit output current, IOS.

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PARAMETER	FROM (INPUT)	TO (OUTPUT)	(OUTPUT) $T_{A} = MIN \text{ to MAX}^{\dagger}$ $SN74ALS651A$			
f _{max}			40	MAX	MHz	
tPLH			8	32	IVIII IZ	
tPHL	CLKBA or CLKAB	A or B	5	17	ns	
t _{PLH}			2	18		
tPHL	A or B	B or A	2	10	ns	
tPLH	SBA or SAB‡		8	38	ns	
tPHL	(with A or B high)	A or B	6	21		
tPLH	SBA or SAB‡		8	25	ns	
tPHL	(with A or B low)	A or B	7	21		
t _{PZH}			3	20		
t _{PZL}	O EBA	A	5	18	ns	
t _{PHZ}	<u> </u>		2	9		
t _{PLZ}	OEBA	A	3	12	ns	
tPZH	0.515	_	3	22		
t _{PZL}	OEAB	В	6	21	ns	
t _{PHZ}	OFAR	5	2	12	ns	
tPLZ	OEAB	В	2	14		

[†] For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.

[‡] These parameters are measured with the internal output state of the storage register opposite that of the bus input.

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PARAMETER	FROM (INPUT)	TO (OUTPUT)	C R R	V_{CC} = 4.5 V to 5.5 V, C_L = 50 pF, $R1$ = 500 Ω , $R2$ = 500 Ω , T_A = MIN to MAX [†]				
			SN54A	LS652	SN74AL	S652A]	
			MIN	MAX	MIN	MAX		
f _{max}			35		40		MHz	
^t PLH	CLKBA or CLKAB	A or B	10	35	8	30	ns	
t _{PHL}	CLNDA OI CLNAD	AOIB	5	20	5	17	115	
^t PLH	A or B	B or A	5	20	4	18	ns	
^t PHL	AUD	BUIA	3	15	3	12		
^t PLH	SBA or SAB‡	A or B	15	40	8	35	ns	
^t PHL	(with A or B high)	AOID	6	23	6	20		
tPLH	SBA or SAB‡	A or B	8	30	8	25	ns	
t _{PHL}	(with A or B low)	AOIB	5	24	5	20	ns	
^t PZH	OEBA	A	3	20	3	17	ne	
t _{PZL}	OEBA	^	5	22	5	18	ns	
t _{PHZ}	OEBA	А	1	12	1	10	ns	
t _{PLZ}	OEBA	A	2	20	2	16	115	
^t PZH	OEAB	В	8	25	3	22	ns	
tPZL	OLAB	ь	6	21	5	18	1115	
^t PHZ	OEAB	В	1	12	1	10	ns	
^t PLZ	OLAB	ь	2	21	2	16	1115	

[†] For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.

[‡] These parameters are measured with the internal output state of the storage register opposite that of the bus input.

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absolute maximum rating	as over operatin	a free-air tem	perature range	(unless	otherwise no	oted)†
abootato maximam rating	go ovoi opoiatii	g noo an tom	porataro rarigo	(4111000	• · · · · · · · · · · · · · · · · · · ·	J. C. C. J.

Supply voltage, V _{CC}	7 V
Input voltage, V _I : All inputs and A I/O ports	7 V
B I/O ports	5.5 V
Operating free-air temperature range, T _A : SN54ALS653	
SN74ALS653, SN74ALS	654 0°C to 70°C
Storage temperature range, T _{sta}	65°C to 150°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

recommended operating conditions

			SN	54ALS6	53	SN	UNIT		
			MIN	NOM	MAX	MIN	NOM	MAX	UNIT
Vcc	Supply voltage		4.5	5	5.5	4.5	5	5.5	V
V_{IH}	High-level input voltage		2			2			V
V_{IL}	Low-level input voltage				0.7			0.8	V
Vон	High-level output voltage	A ports			5.5			5.5	V
IOH	High-level output current B ports				-12			-15	mA
lOL	Low-level output current				12			24	mA
fclock	Clock frequency		0		25	0		35	MHz
	Pulse duration	CLKBA or CLKAB high	20			14.5			no
t _W	Pulse duration	CLKBA or CLKAB low	20			14.5			ns
t _{su}	Setup time before CLKAB↑ or CLKBA↑	A or B	15			10			ns
th	Hold time after CLKAB↑ or CLKBA↑ A or B		5			0			ns
TA	Operating free-air temperature		-55		125	0		70	°C

recommended operating conditions

			SN	UNIT		
			MIN	NOM	MAX	UNII
Vcc	Supply voltage		4.5	5	5.5	V
VIH	High-level input voltage		2			V
VIL	Low-level input voltage	l input voltage			0.8	V
Vон	High-level output voltage	A ports			5.5	V
lOH	High-level output current	B ports			-15	mA
loL	Low-level output current				24	mA
fclock	Clock frequency		0		35	MHz
	Pulse duration	CLKBA or CLKAB high	14.5			ne
t _W	Fuise duration	CLKBA or CLKAB low	14.5			ns
t _{su}	Setup time before CLKAB↑ or CLKBA↑	A or B	10			ns
t _h	Hold time after CLKAB↑ or CLKBA↑	A or B	0			ns
TA	Operating free-air temperature		0		70	°C

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electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

	DAMETER	TECT	CONDITIONS	SN	54ALS6	53	SN7	74ALS6	53	LINUT	
P P	ARAMETER	1531	CONDITIONS	MIN	TYP	MAX	MIN	TYP†	MAX	UNIT	
٧ıK		$V_{CC} = 4.5 \text{ V},$	$I_{I} = -18 \text{ mA}$			-1.2			-1.2	V	
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V},$	$I_{OH} = -0.4 \text{ mA}$	V _{CC} -2			V _{CC} -2				
VOH B	B ports	V _{CC} = 4.5 V	$I_{OH} = -3 \text{ mA}$	2.4	3.2		2.4	3.2		٧	
VOH	D ports		$I_{OH} = -12 \text{ mA}$	2							
			I _{OH} = -15 mA				2				
V/01		V _{CC} = 4.5 V	$I_{OL} = 12 \text{ mA}$		0.25	0.4		0.25	0.4		
VOL	VCC = 4.5 V	I _{OL} = 24 mA					0.35	0.5	V		
1.	Control inputs	$V_{CC} = 5.5 \text{ V},$	V _I = 7 V			0.1			0.1	mA	
1	A or B ports	$V_{CC} = 5.5 \text{ V},$	V _I = 5.5 V			0.1			0.1		
	Control inputs	V 55V	557			20			20	•	
lн	A or B ports‡	V _{CC} = 5.5 V,	V _I = 2.7 V			20			20	μΑ	
	Control inputs	v 55V				-0.2			-0.2		
¹IL	A or B ports‡	V _{CC} = 5.5 V,	$V_I = 0.4 V$			-0.2			-0.2	mA	
ІОН	A ports	V _{CC} = 4.5 V,	V _{OH} = 5.5 V			0.1			0.1	mA	
IO§	B ports	$V_{CC} = 5.5 \text{ V},$	V _O = 2.25 V	-20		-112	-30		-112	mA	
	•		Outputs high		47	76		47	76		
ICC		V _{CC} = 5.5 V	Outputs low		55	88		55	88	mA	
			Outputs disabled		55	88		55	88		

[†] All typical values are at V_{CC} = 5 V, T_A = 25°C. ‡ For I/O ports, the parameters I_{IH} and I_{IL} include the off-state output current.

[§] The output conditions have been chosen to produce a current that closely approximates one-half of the true short-circuit output current, IOS.

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electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

	DADAMETED	TEST COL	NDITIONS	S	N74ALS6	54	LINUT
	PARAMETER	1521 CO	NDITIONS	MIN	TYP [†]	MAX	UNIT
VIK		$V_{CC} = 4.5 \text{ V},$	$I_{I} = -18 \text{ mA}$			-1.2	V
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V},$	$I_{OH} = -0.4 \text{ mA}$	V _{CC} -	2		
Vон	B ports	V _{CC} = 4.5 V	$I_{OH} = -3 \text{ mA}$	2.4	3.2		V
		∨CC = 4.5 v	$I_{OH} = -15 \text{ mA}$	2			
VOL		V _{CC} = 4.5 V	I _{OL} = 12 mA		0.25	0.4	V
VOL		∨CC = 4.5 V	$I_{OL} = 24 \text{ mA}$		0.35	0.5	V
1.	Control inputs	$V_{CC} = 5.5 \text{ V},$	V _I = 7 V			0.1	mA
†ı	A or B ports	V _{CC} = 5.5 V,	V _I = 5.5 V			0.1	IIIA
I	Control inputs	V	V _I = 2.7 V			20	
ΉΗ	A or B ports‡	$V_{CC} = 5.5 V,$	V = 2.1 V			20	μΑ
1	Control inputs	V00 - 5 5 V	V _I = 0.4 V			-0.2	mA
ll l	A or B ports‡	V _{CC} = 5.5 V,	V = 0.4 V			-0.2	IIIA
ІОН	A ports	V _{CC} = 4.5 V,	V _{OH} = 5.5 V			0.1	mA
IO§	B ports	V _{CC} = 5.5 V,	V _O = 2.25 V	-30		-112	mA
			Outputs high		47	76	
Icc		V _{CC} = 5.5 V	Outputs low		55	88	mA
		00 -	Outputs disabled		55	88	

[†] All typical values are at $V_{CC} = 5 \text{ V}$, $T_A = 25^{\circ}\text{C}$.

[‡] For I/O ports, the parameters I_{IH} and I_{IL} include the off-state output current.

[§] The output conditions have been chosen to produce a current that closely approximates one-half of the true short-circuit output current, IOS.

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PARAMETER	FROM (INPUT)	TO (OUTPUT)	C _L = 50 R _L = 68 R1 = R2	V_{CC} = 4.5 V to 5.5 V, C_L = 50 pF, R_L = 680 Ω (A outputs), R1 = R2 = 500 Ω (B outputs), T_A = MIN to MAX †				
			SN54A	LS653	SN74A	LS653		
			MIN	MAX	MIN	MAX		
f _{max}			25		35		MHz	
^t PLH	CLKBA	А	16	71	16	64	ns	
^t PHL	CLNDA	A	6	24	6	22	115	
^t PLH	CLKAB	В	10	35	10	30	ns	
^t PHL	CLNAD	В	5	20	5	17	115	
^t PLH	A	В	5	20	5	18	ns	
^t PHL	^		1.5	18	2	15	115	
^t PLH	В	A	8	63	12	56	ns	
t _{PHL}	В	A	2	18	2	15	115	
^t PLH	SBA [‡]	A	12	68	19	62	ns	
^t PHL	(with B high)	^	5	27	5	25	115	
^t PLH	SBA [‡]	A	12	68	19	62	ns	
^t PHL	(with B low)	A	5	27	5	25	115	
^t PLH	SAB [‡]	В	8	30	15	35	ns	
^t PHL	(with A high)	В	6	25	6	22	115	
^t PLH	SAB‡	В	12	40	8	25	ns	
^t PHL	(with A low)	Ь	6	25	6	22	115	
^t PLH	 OEBA	A	6	35	6	30	ns	
^t PHL	OEBA	^	6	27	6	24	115	
^t PZH	OEAB	ь	7	25	8	22	nc	
^t PZL	OLAB	В	6	25	6	22	ns	
^t PHZ	OEAB	ь	1	16	1	14	nc	
t _{PLZ}	OEAD	В	2	21	2	16	ns	

[†] For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.

[‡] These parameters are measured with the internal output state of the storage register opposite that of the bus input.

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PARAMETER	FROM (INPUT)	TO (OUTPUT)	V_{CC} = 4.5 V to 5.5 V, C_L = 50 pF, R_L = 680 Ω (A outputs), $R1$ = $R2$ = 500 Ω (B outputs), T_A = MIN to MAX [†]	UNIT
			MIN MAX	
f _{max}			35	MHz
^t PLH	CLKBA	А	16 64	ns
t _{PHL}	CLNDA	A	6 22	115
^t PLH	CLKAB	В	10 30	ns
^t PHL	CLNAD	В	5 17	115
t _{PLH}	A	В	5 18	
t _{PHL}		Ь	2 15	ns
t _{PLH}	В	А	12 56	
t _{PHL}		^	2 21	ns
t _{PLH}	SBA [‡]	Α	19 62	ns
t _{PHL}	(with B low)	A	5 25	113
t _{PLH}	SBA‡	А	19 62	ns
^t PHL	(with B high)	A	5 25	115
^t PLH	SAB [‡]	В	15 35	ns
^t PHL	(with A low)	В	6 22	115
t _{PLH}	SAB‡	В	8 25	ns
^t PHL	(with A high)	Ь	6 22	115
t _{PLH}	OEBA	А	6 30	ne
t _{PHL}	OEBA	A	6 24	ns
^t PZH	OEAB	В	6 22	ns
t _{PZL}	OLAB	J J	6 22	113
^t PHZ	OEAB	В	1 14	ne
t _{PLZ}	UEAD	D	2 16	ns

[†] For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.

[‡] These parameters are measured with the internal output state of the storage register opposite that of the bus input.

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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage, V _{CC}	7 V
Input voltage, V _I : Control inputs	7 V
I/O ports	5.5 V
Operating free-air temperature range, T _A : SN54AS651, SN54AS652	–55°C to 125°C
SN74AS651, SN74AS652	0°C to 70°C
Storage temperature range, T _{stg}	65°C to 150°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

recommended operating conditions

			SN54AS651 SN54AS652			SN74AS651 SN74AS652			UNIT
			MIN	NOM	MAX	MIN	NOM	MAX	
Vcc	Supply voltage		4.5	5	5.5	4.5	5	5.5	V
VIH	High-level input voltage		2			2			V
VIL	Low-level input voltage				0.8			0.8	V
ЮН	High-level output current				-12			-15	mA
loL	Low-level output current				32			48	mA
fclock*	Clock frequency		0		75	0		90	MHz
. *	Pulse duration	CLKBA or CLKAB high	6			5			ns
t _W *	ruise duration	CLKBA or CLKAB low	7			6			115
t _{su} *	Setup time before CLKAB↑ or CLKBA↑	A or B	7			6			ns
th*	Hold time after CLKAB↑ or CLKBA	A or B	0			0			ns
TA	Operating free-air temperature		-55		125	0		70	°C

^{*} On products compliant to MIL-PRF-38535, this parameter is based on characterized data but is not production tested.

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electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CO	ONDITIONS		N54AS65 N54AS65	-		174AS65 174AS65		UNIT
				MIN	TYP [†]	MAX	MIN	TYP [†]	MAX	
٧ıK		V _{CC} = 4.5 V,	$I_{I} = -18 \text{ mA}$			-1.2			-1.2	V
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V},$	$I_{OH} = -2 \text{ mA}$	V _{CC} -2	!		V _{CC} -2			
\ _{\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\}			$I_{OH} = -3 \text{ mA}$	2.4	3.2		2.4	3.2		v
VOH		V _{CC} = 4.5 V	$I_{OH} = -12 \text{ mA}$	2]
			$I_{OH} = -15 \text{ mA}$				2			
VOL		V _{CC} = 4.5 V	I _{OL} = 32 mA		0.25	0.5				V
		VCC = 4.5 V	I _{OL} = 48 mA					0.35	0.5	v
†į	Control inputs	V _{CC} = 5.5 V,	V _I = 7 V			0.1			0.1	mA
	A or B ports	V _{CC} = 5.5 V,	V _I = 5.5 V			0.1			0.1	0.1
	Control inputs	V 55V	V 07V			20			20	•
lіН	A or B ports‡	V _{CC} = 5.5 V,	V _I = 2.7 V			70			70	μΑ
	Control input	v 55V				-0.5			-0.5	•
¹ı∟	A or B ports‡	$V_{CC} = 5.5 \text{ V},$	V _I = 0.4 V			-0.75			-0.75	mA
IO§		V _{CC} = 5.5 V,	V _O = 2.25 V	-30		-112	-30		-112	mA
			Outputs high		110	185		110	185	4 1
	′AS651	V _{CC} = 5.5 V	Outputs low		120	195		120	195	
			Outputs disabled		130	195		130	195	
Icc			Outputs high		120	195		120	195	
	′AS652	V _{CC} = 5.5 V	Outputs low		130	211		130	211	
			Outputs disabled		130	211		130	211	

[†] All typical values are at V_{CC} = 5 V, T_A = 25 °C.

[‡] For I/O ports, the parameters I_{IH} and I_{IL} include the off-state output current.

[§] The output conditions have been chosen to produce a current that closely approximates one-half of the true short-circuit output current, los.

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PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _C C _L R1 R2 T _A	UNIT			
			SN54A	\S651	SN74A	S651	
			MIN	MAX	MIN	MAX	
f _{max} *			75		90		MHz
t _{PLH}	CLKBA or CLKAB	A or B	2	11	2	8.5	ns
^t PHL	GENDA OF GENAD	A 01 B	2	10	2	9	113
^t PLH	A or B	B or A	2	12	2	8	ns
^t PHL	A OI D	BOIN	1	8	1	7	113
^t PLH	SBA or SAB‡	A or B	2	15	2	11	ns
^t PHL	SBA UI SAB+	A 01 B	2	11	2	9	113
^t PZH	 OEBA	А	2	11	2	10	ns
t _{PZL}	OEBA	۸	3	18	3	16	113
^t PHZ	 OEBA	А	2	10	2	9	ns
t _{PLZ}	OEBA	7	2	10	2	9	115
^t PZH	OEAB	В	3	12	3	11	ns
^t PZL	OLAD	5	3	20	3	16	113
^t PHZ	OEAB	В	2	11	2	10	ns
t _{PLZ}	OLAD	В	2	12	2	11	115

^{*} On products compliant to MIL-PRF-38535, this parameter is based on characterized data but is not production tested.

[†] For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.

[‡] These parameters are measured with the internal output state of the storage register opposite that of the bus input.

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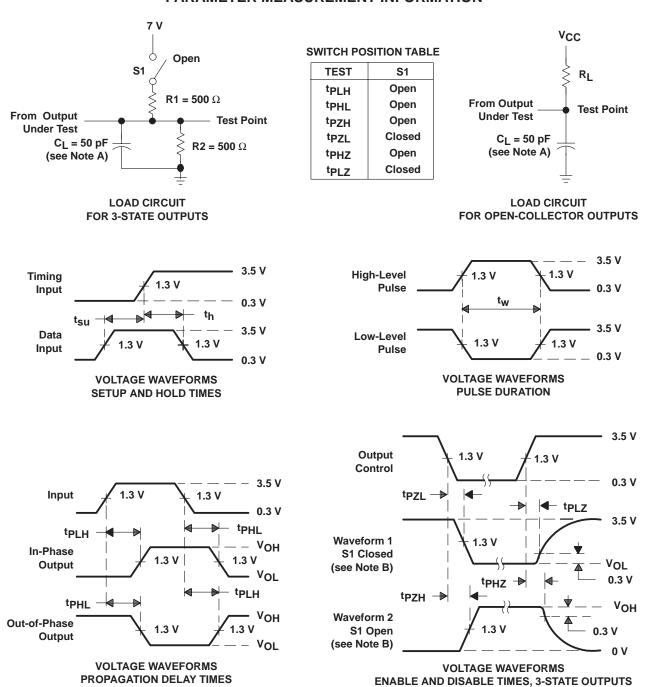
PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _C	UNIT			
			SN54A	\S652	SN74A	S652	
			MIN	MAX	TYP	MAX	
f _{max} *			75		90		MHz
tPLH	CLKBA or CLKAB	A or B	2	11	2	8.5	ns
t _{PHL}	CENDA OF CENAD	AOIB	2	10	2	9	115
t _{PLH}	A or B	B or A	2	12	2	9	ns
t _{PHL}		BOIA	1	8	1	7	115
tPLH	SBA or SAB‡	A or B	2	15	2	11	ns
t _{PHL}	284 of 248+	AUD	2	11	2	9	115
^t PZH	OEBA	А	2	11	2	10	ns
t _{PZL}	OEBA	^	3	18	3	16	115
^t PHZ	 OEBA	А	2	10	2	9	ns
t _{PLZ}	OEBA	Α	2	10	2	9	115
^t PZH	OEAB	В	3	12	3	11	ns
tPZL	OLAD	<u> </u>	3	20	3	16	115
^t PHZ	OEAB	В	2	11	2	10	ns
^t PLZ	OLAD	ט	2	12	2	11	115

^{*} On products compliant to MIL-PRF-38535, this parameter is based on characterized data but is not production tested.

[†] For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.

[‡] These parameters are measured with the internal output state of the storage register opposite that of the bus input.

PARAMETER MEASUREMENT INFORMATION



NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 1 MHz, $Z_0 = 50 \ \Omega$, $t_f \leq 2 \ ns$, $t_f \leq 2 \ ns$.
- D. The outputs are measured one at a time with one transition per measurement.

Figure 2. Load Circuits and Voltage Waveforms



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